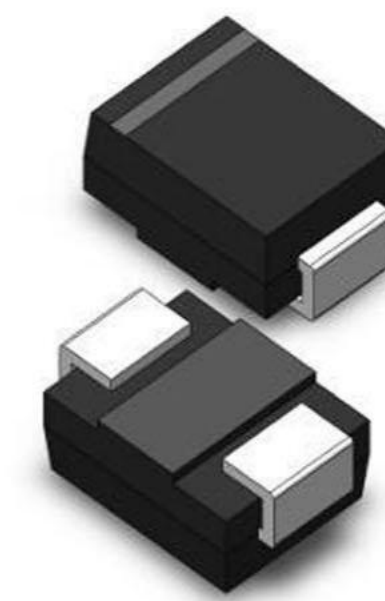


OM SENI

MURS120T3G Series surface Mount Ultrafast Power Rectifiers

MURS105T3G THRU MURS MURS160T3G

ULTRAFAST RECTIFIERS
1.0 AMPERE
50–600 VOLTS



SMB
CASE 403A

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

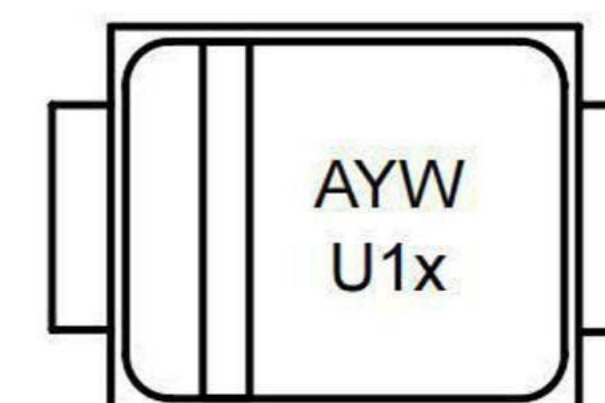
Features

- Pb-Free Packages are Available
- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- High Temperature Glass Passivated Junction
- Low Forward Voltage Drop (0.71 to 1.05 Volts Max @ 1.0 A, $T_J = 150^\circ\text{C}$)

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Polarity Band Indicates Cathode Lead

MARKING DIAGRAM



U1 = Device Code
x = A, B, C, D, G or J
A = Assembly Location
Y = Year
W = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the table on page 2 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

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MAXIMUM RATINGS

Rating	Symbol	MURS						Unit
		105T3G	110T3G	115T3G	120T3G	140T3G	160T3G	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	150	200	400	600	V
Average Rectified Forward Current	$I_{F(AV)}$	1.0 @ $T_L = 155^{\circ}\text{C}$ 2.0 @ $T_L = 145^{\circ}\text{C}$				1.0 @ $T_L = 150^{\circ}\text{C}$ 2.0 @ $T_L = 125^{\circ}\text{C}$		A
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I_{FSM}	40				35		A
Operating Junction Temperature	T_J	- 65 to +175						$^{\circ}\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Lead ($T_L = 25^\circ\text{C}$)	$R_{\theta JL}$	13	$^\circ\text{C/W}$
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ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 1.0\text{ A}$, $T_J = 25^\circ\text{C}$) ($i_F = 1.0\text{ A}$, $T_J = 150^\circ\text{C}$)	V_F	0.875 0.71	1.25 1.05	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_J = 25^\circ\text{C}$) (Rated DC Voltage, $T_J = 150^\circ\text{C}$)	i_R	2.0 50	5.0 150	μA
Maximum Reverse Recovery Time ($i_F = 1.0\text{ A}$, $di/dt = 50\text{ A}/\mu\text{s}$) ($i_F = 0.5\text{ A}$, $i_R = 1.0\text{ A}$, I_R to 0.25 A)	t_{rr}	35 25	75 50	ns
Maximum Forward Recovery Time ($i_F = 1.0\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, Rec. to 1.0 V)	t_{fr}	25	50	ns

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$.

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MURS105T3G	U1A	SMB (Pb-Free)	2500 Units/Tape & Reel
MURS110T3G	U1B	SMB (Pb-Free)	2500 Units/Tape & Reel
MURS115T3G	U1C	SMB (Pb-Free)	2500 Units/Tape & Reel
MURS120T3G	U1D	SMB (Pb-Free)	2500 Units/Tape & Reel
MURS140T3G	U1G	SMB (Pb-Free)	2500 Units/Tape & Reel
MURS160T3G	U1J	SMB (Pb-Free)	2500 Units/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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MURS105T3G, MURS110T3G, MURS115T3G, MURS120T3G

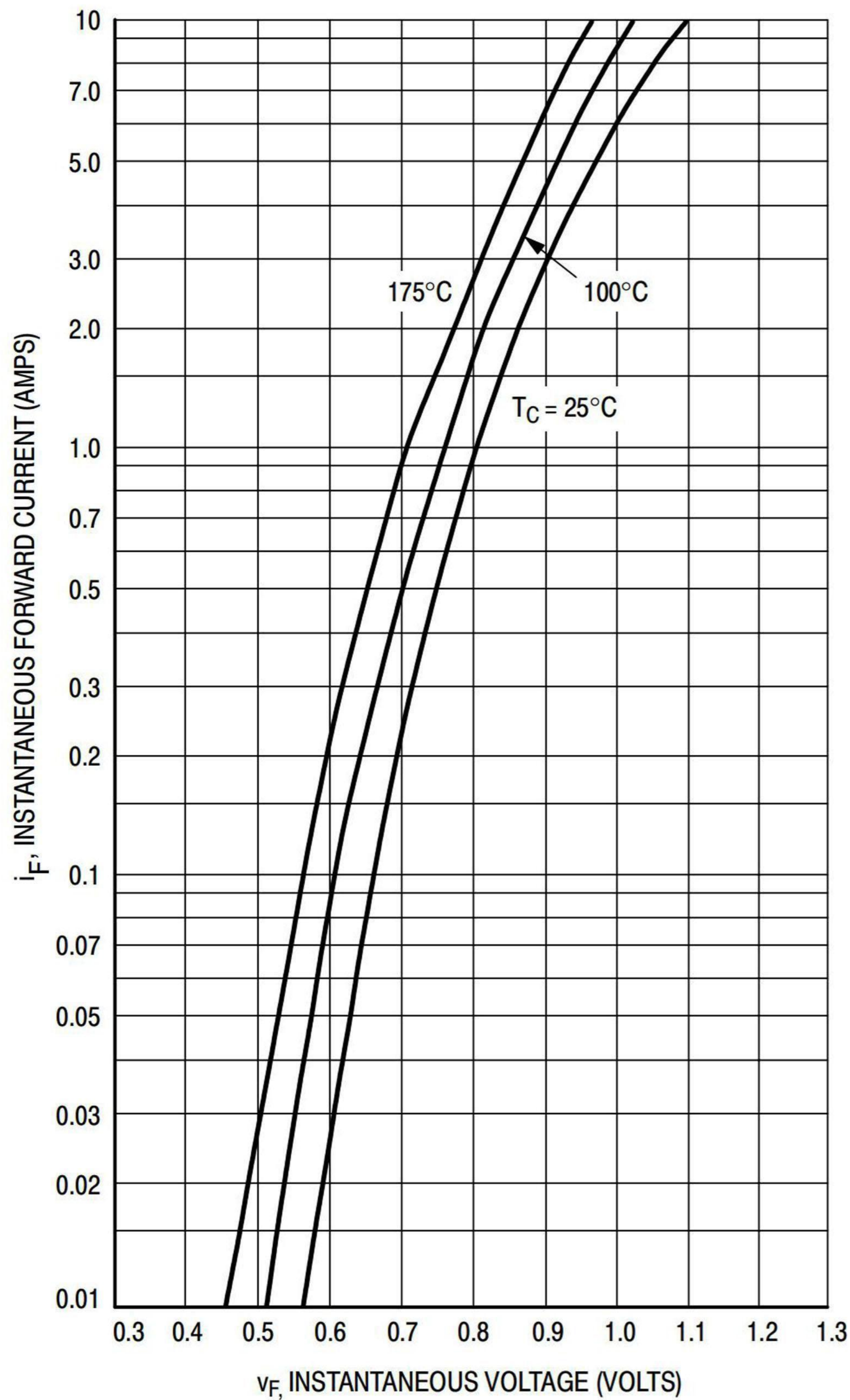


Figure 1. Typical Forward Voltage

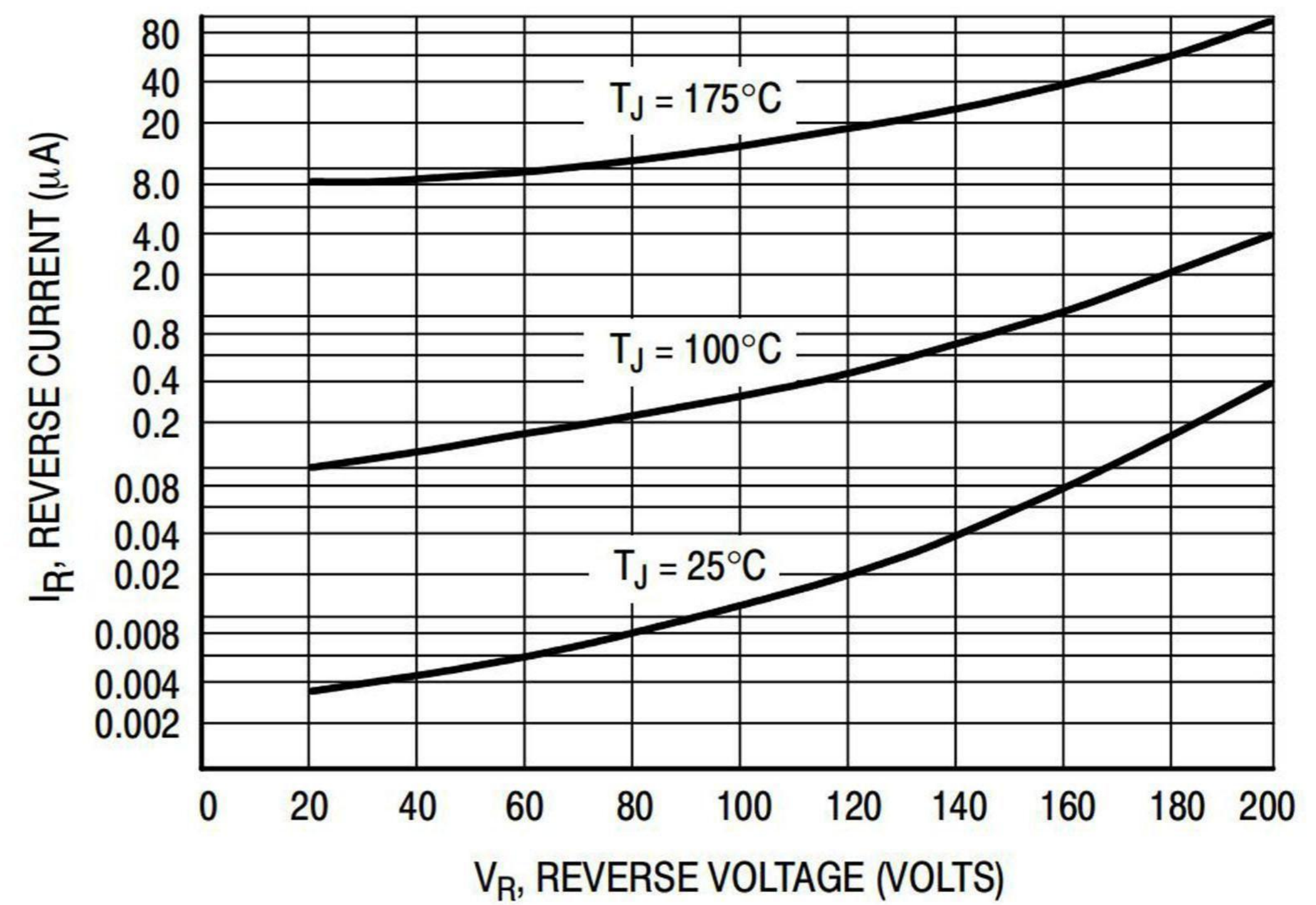


Figure 2. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if applied V_R is sufficiently below rated V_R .

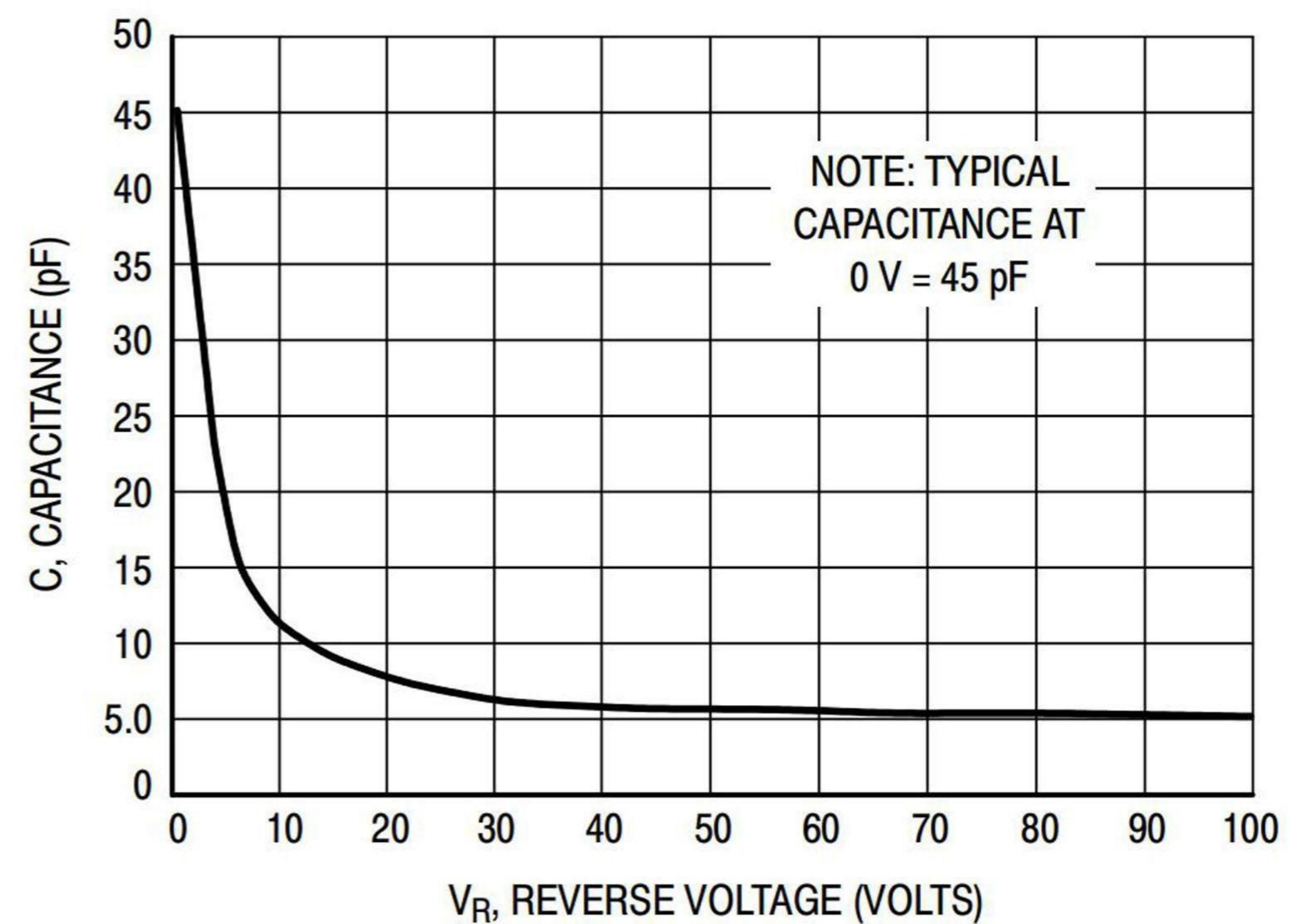


Figure 3. Typical Capacitance

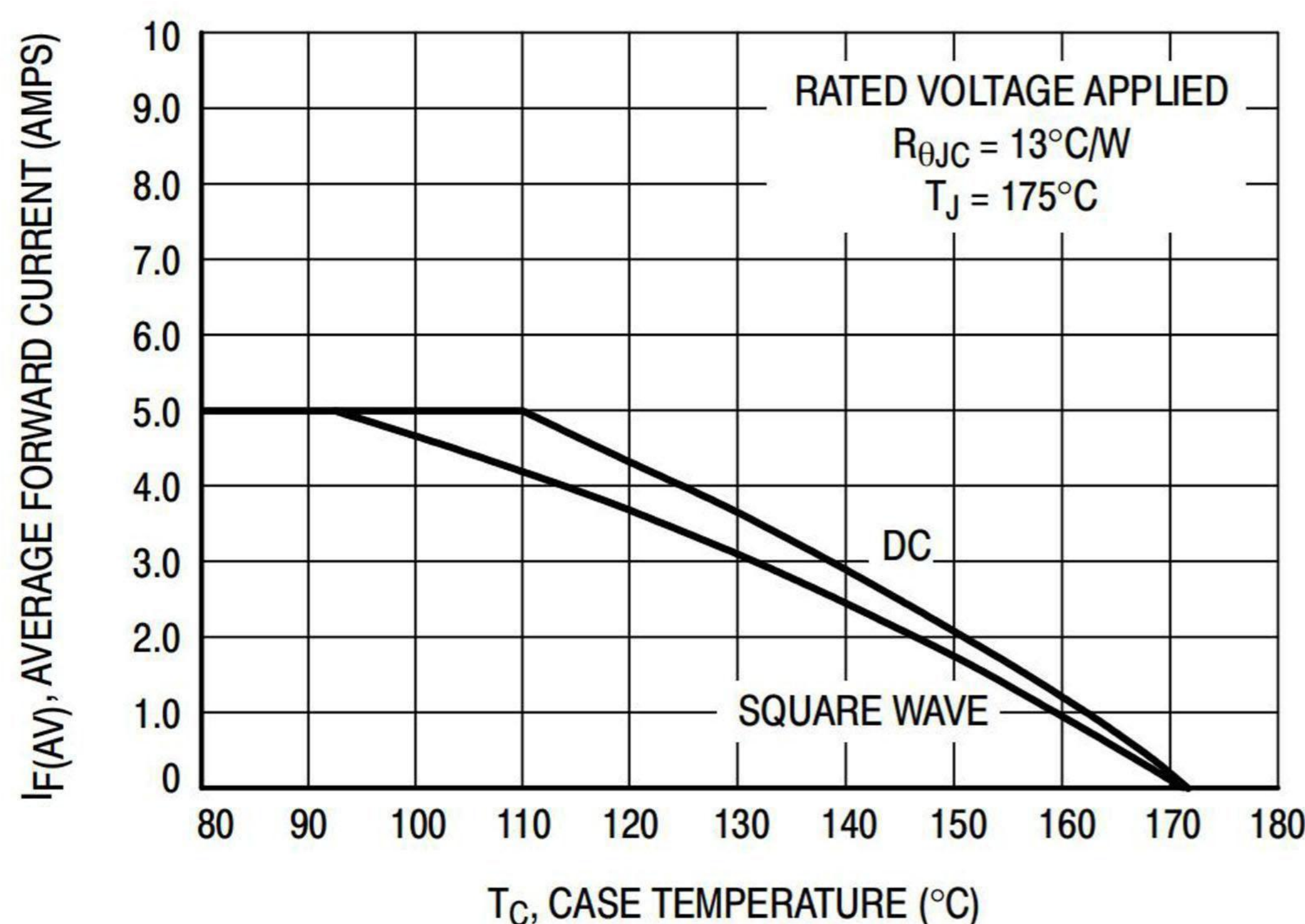


Figure 4. Current Derating, Case

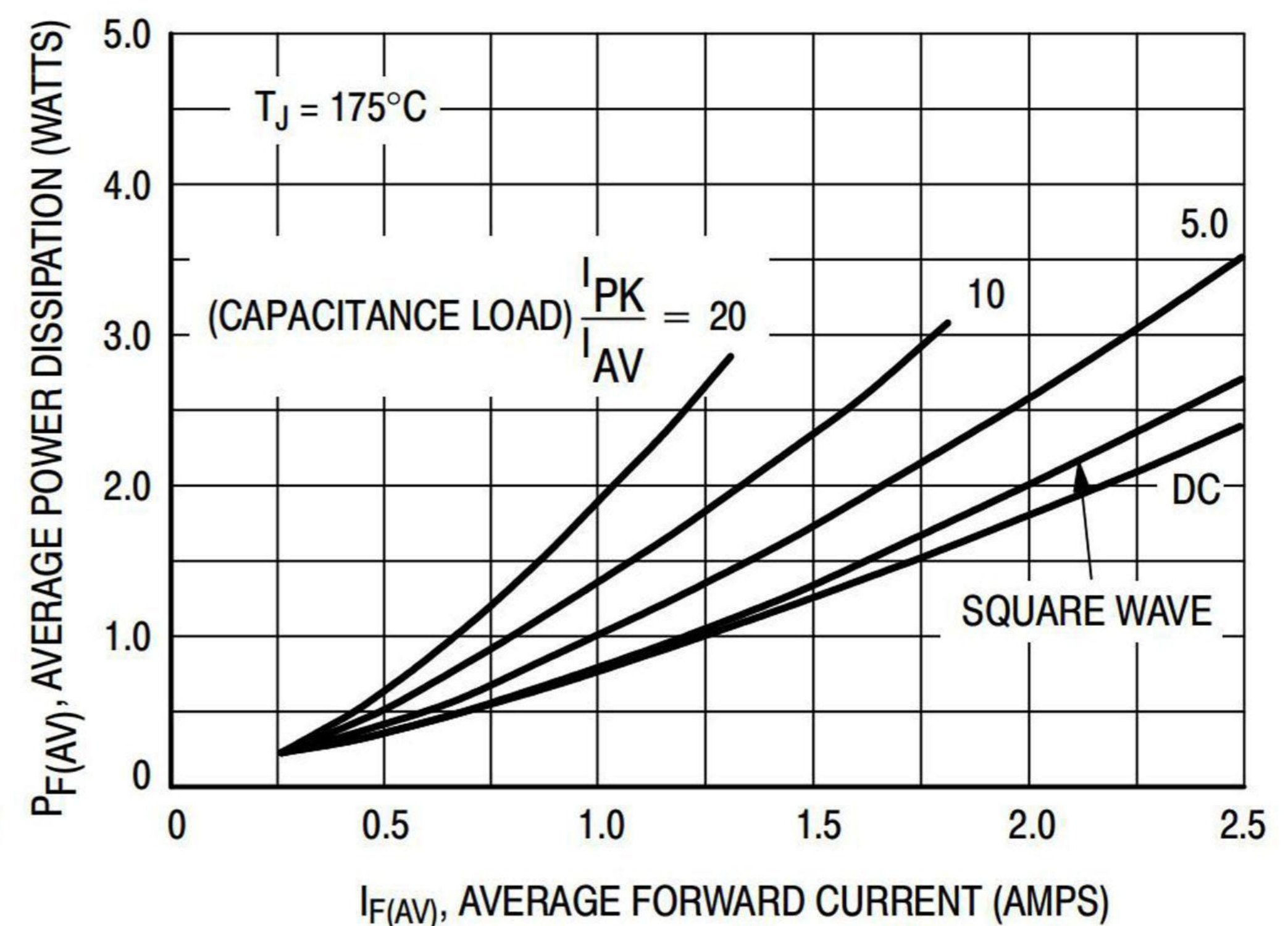


Figure 5. Power Dissipation

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MURS140T3G, MURS160T3G

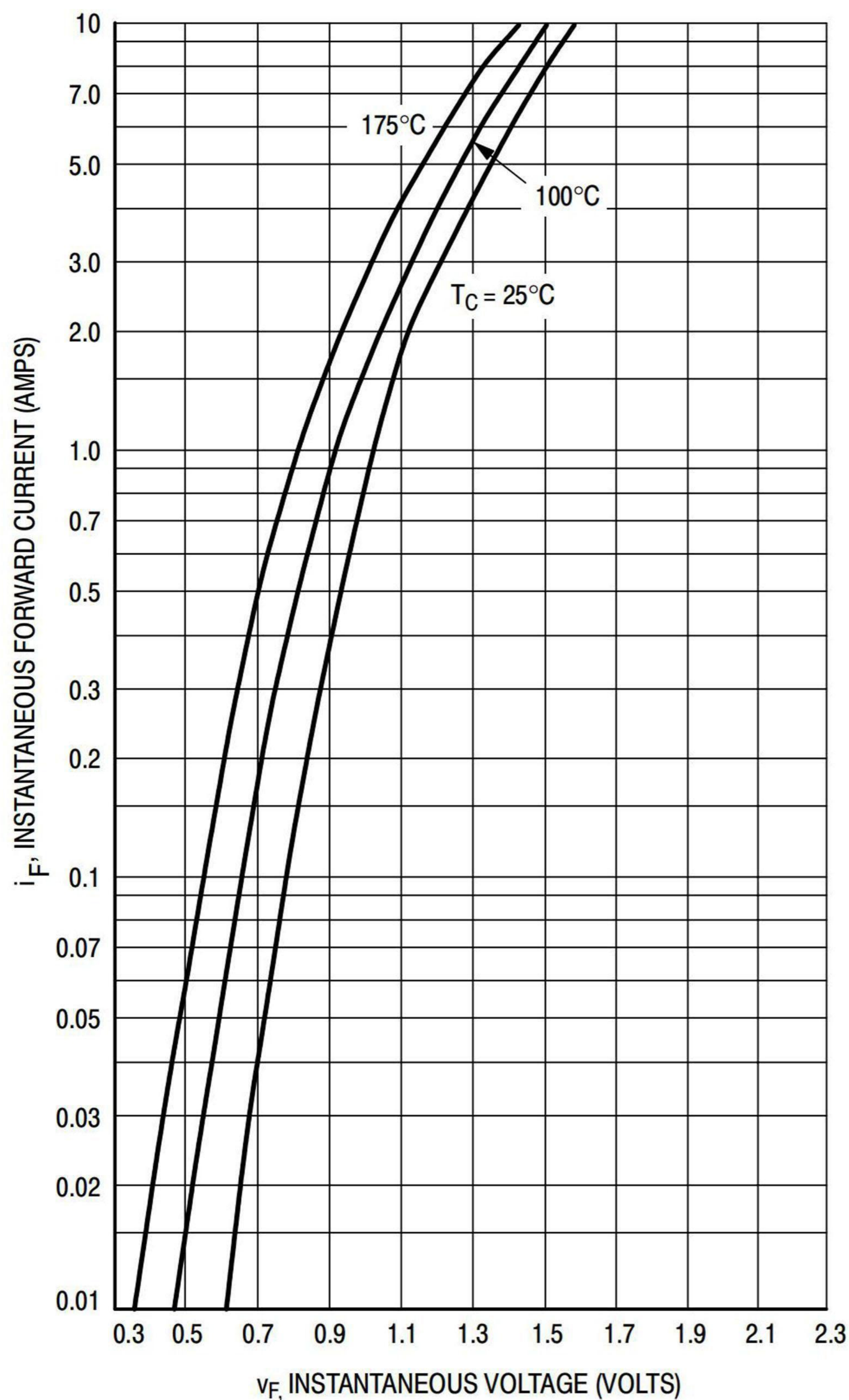


Figure 6. Typical Forward Voltage

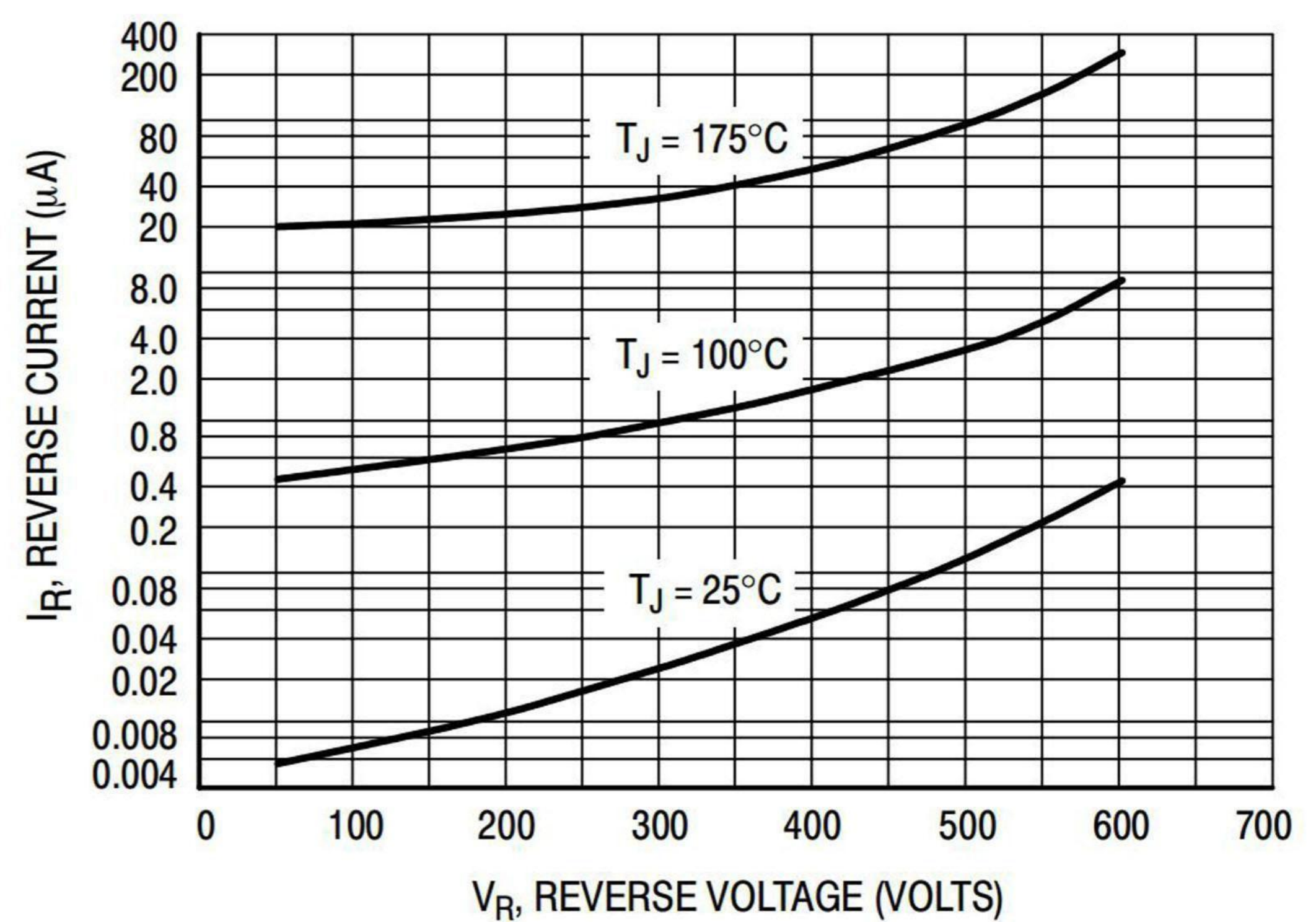


Figure 7. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if applied V_R is sufficiently below rated V_R .

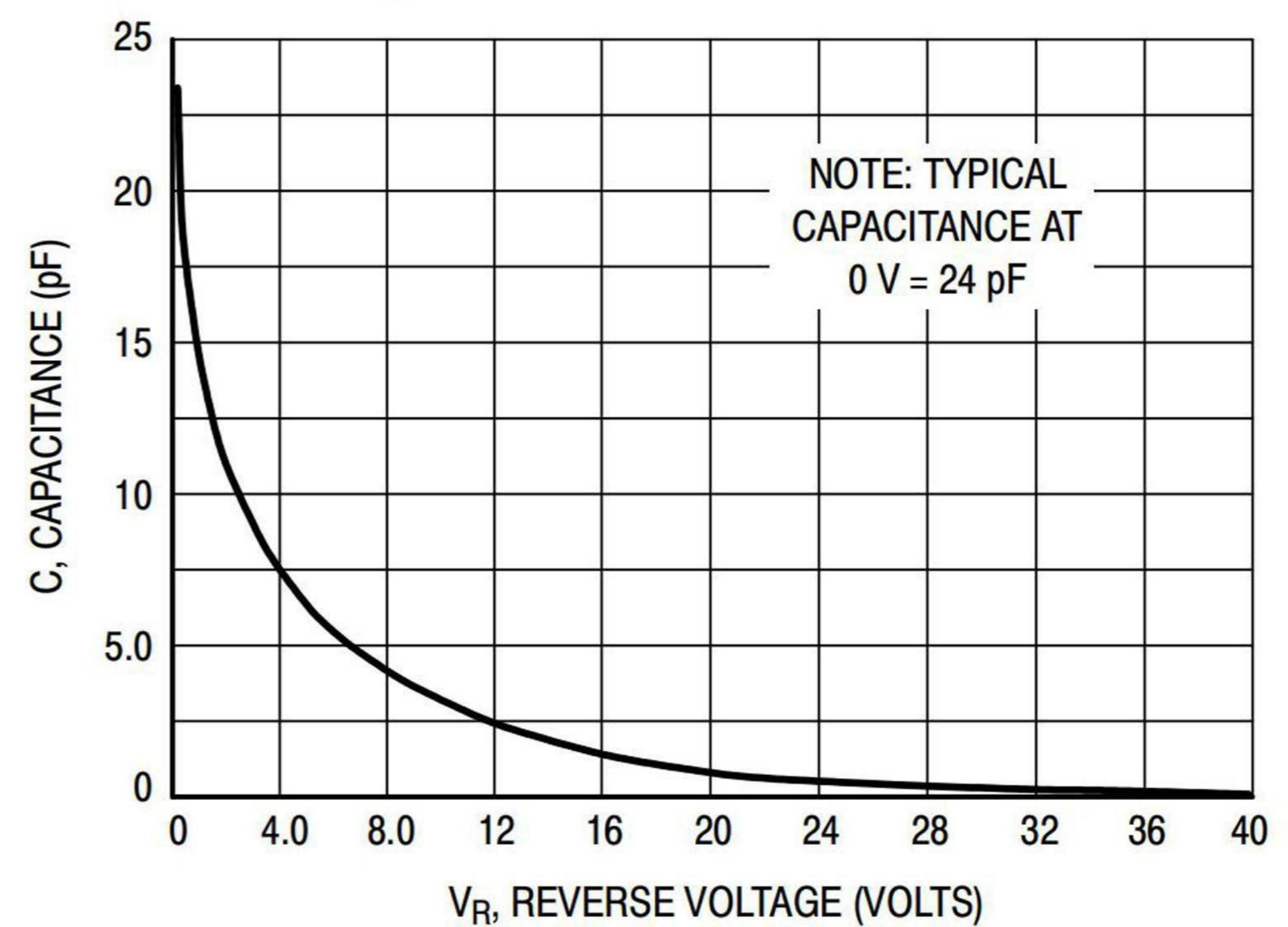


Figure 8. Typical Capacitance

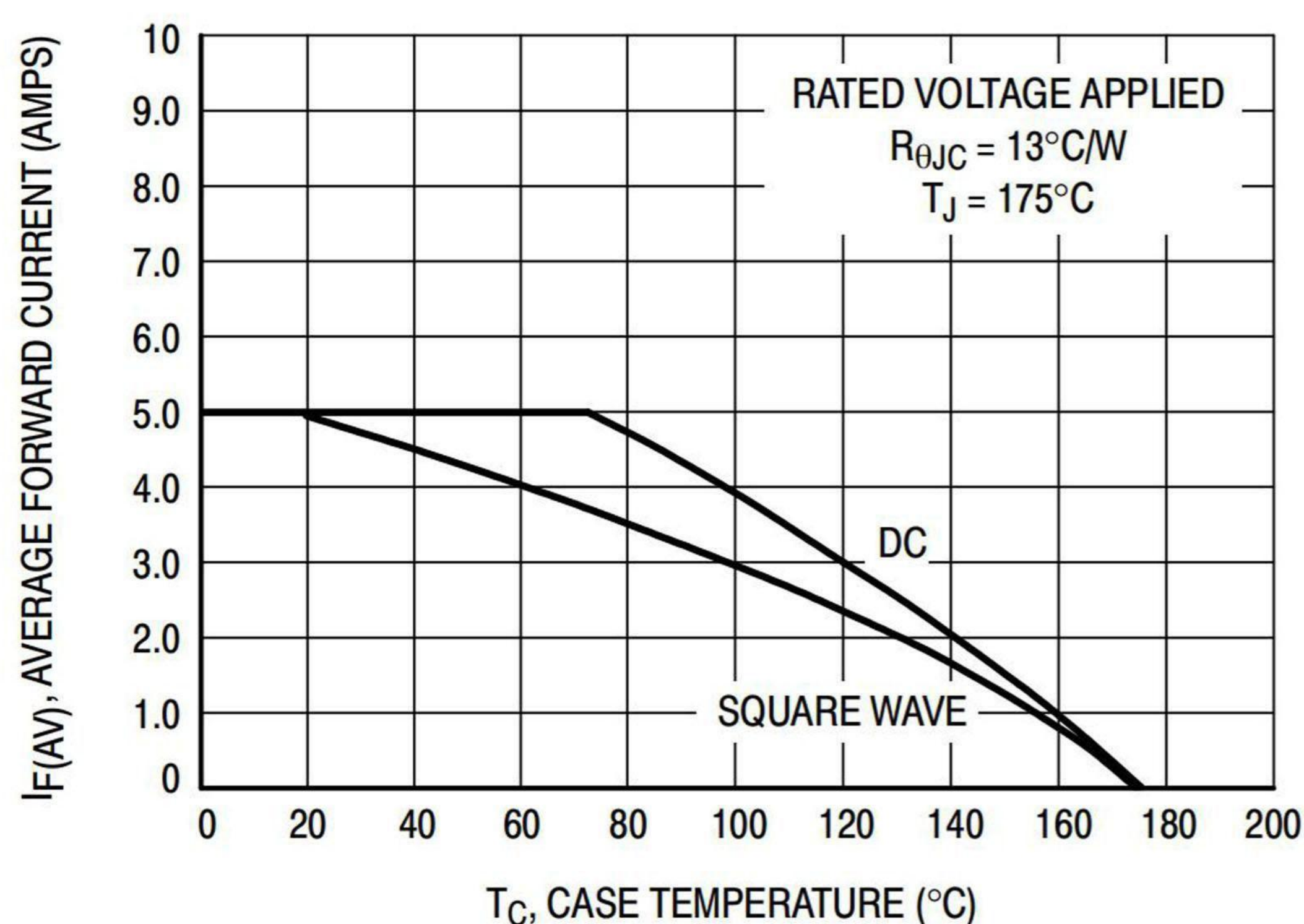


Figure 9. Current Derating, Case

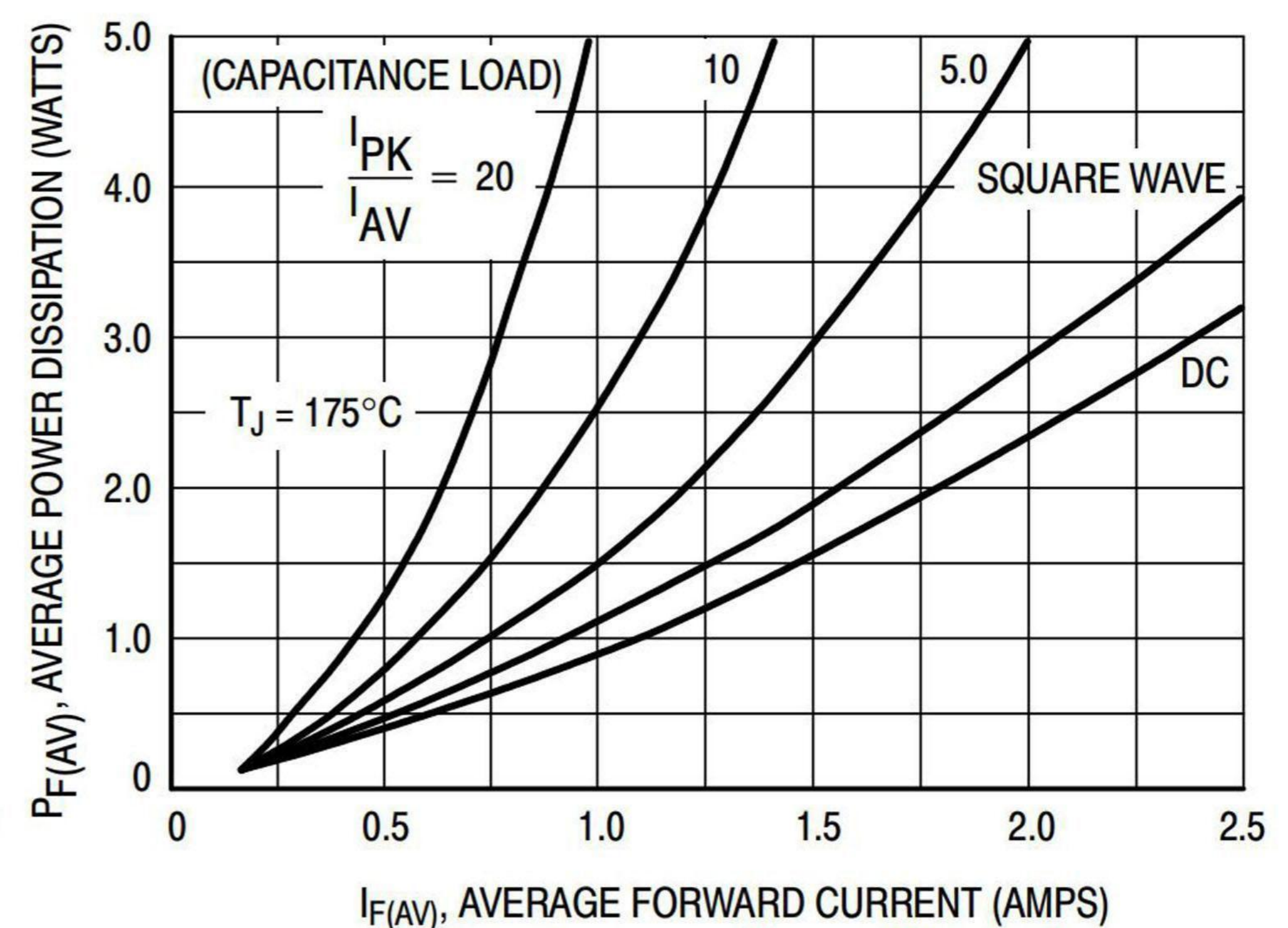


Figure 10. Power Dissipation

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Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SMB	R3	0.098	2500	5000	25000	13

Package Outline Dimensions (SMB/DO-214AA)

Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.85	2.21	0.073	0.087
B	4.25	4.85	0.167	0.191
C	3.30	3.94	0.130	0.155
D	2.15	2.65	0.085	0.104
E	0.75	1.52	0.030	0.060
F	-	0.203	-	0.008
G	5.08	5.59	0.200	0.220
H	0.15	0.31	0.006	0.012

Cathode Band

Suggested Pad Layout

Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
M	2.26	-	0.089	-
J	2.10	-	0.085	-
K	-	2.74	-	0.107